Pb Free Product



NCE0240F

NCE N-Channel Enhancement Mode Power MOSFET

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Description

The NCE0240F uses advanced trench technology and design to provide excellent RDS(ON) with low gate charge. It can be used in a wide variety of applications.

General Features

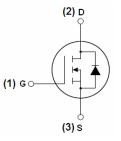
- V_{DS} =200V,I_D =40A $R_{DS(ON)}$ <41m Ω @ V_{GS} =10V
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high EAS
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and high frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% AVds TESTED!



Schematic diagram



Marking and pin assignment



TO-220F top view

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE0240F	NCE0240F	TO-220F	-	-	-

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	200	V
Gate-Source Voltage	V_{GS}	±20	V
Drain Current-Continuous	I _D	40	Α
Drain Current-Continuous(T _C =100 °C)	I _D (100°C)	28	Α
Pulsed Drain Current	I _{DM}	160	Α
Maximum Power Dissipation	P _D	60	W
Derating factor		0.4	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	480	mJ
Operating Junction and Storage Temperature Range	T _J ,T _{STG}	-55 To 175	$^{\circ}$

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Thermal Characteristic

Electrical Characteristics (T_A=25 °C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	200	220	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =200V,V _{GS} =0V	-	-	1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	3.2	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	36.4	41	mΩ
Forward Transconductance	g FS	V _{DS} =25V,I _D =25A	26	-	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{lss}	\/ -05\/\/ -0\/	-	6500	-	PF
Output Capacitance	Coss	V _{DS} =25V,V _{GS} =0V,	-	290	-	PF
Reverse Transfer Capacitance	C _{rss}	C _{rss} F=1.0MHz		220	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}		-	26	-	nS
Turn-on Rise Time	t _r	V_{DD} =30V, I_D =2A, R_L =15 Ω	-	24	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10V, R_{G} =2.5 Ω	-	91	-	nS
Turn-Off Fall Time	t _f	-		39	-	nS
Total Gate Charge	Q_g	\/ -20\/ L -20 A	-	163		nC
Gate-Source Charge	Q _{gs}		-	31		nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	V _{DS} =30V,I _D =30A, V _{GS} =10V		nC	
Drain-Source Diode Characteristics			•			
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =40A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	40	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF = 40A	-	42		nS
Reverse Recovery Charge	Qrr	di/dt = 100A/μs ^(Note3)	-	66		nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

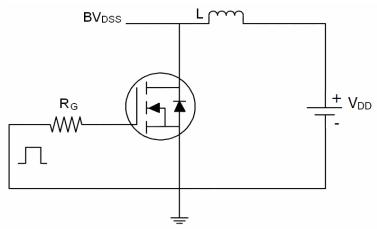
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- **5.** E_{AS} condition: Tj=25 $^{\circ}$ C,V_{DD}=50V,V_G=10V,L=1mH,Rg=25 Ω

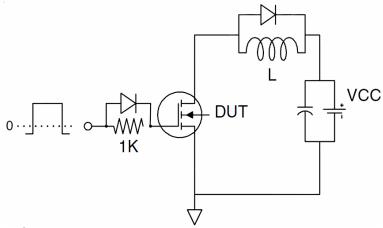


Test Circuit

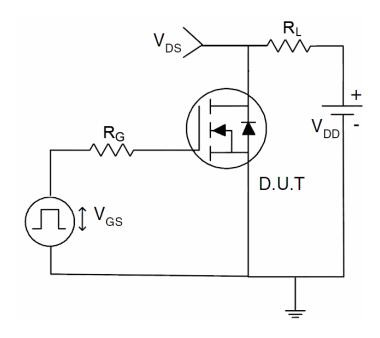
1) E_{AS} test Circuit



2) Gate charge test Circuit



3) Switch Time Test Circuit



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Typical Electrical and Thermal Characteristics (Curves)

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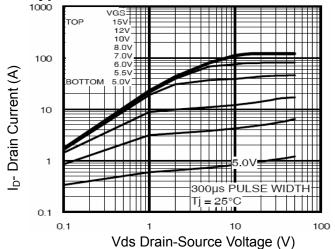


Figure 1 Output Characteristics

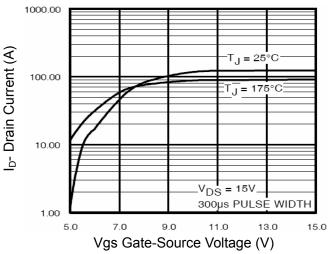


Figure 2 Transfer Characteristics

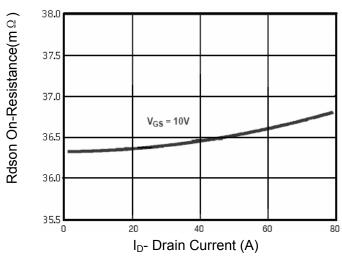


Figure 3 Rdson- Drain Current

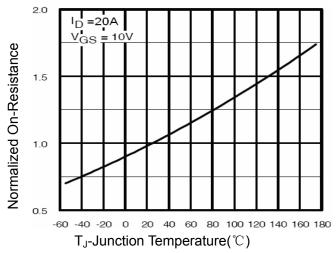


Figure 4 Rdson-JunctionTemperature

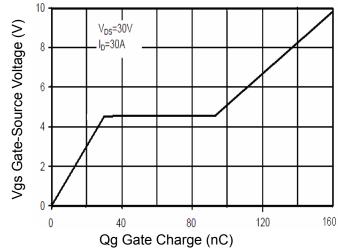


Figure 5 Gate Charge

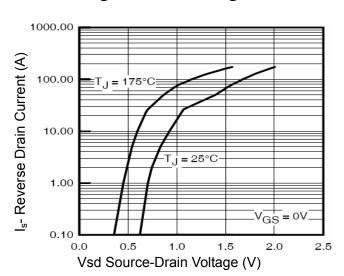


Figure 6 Source- Drain Diode Forward



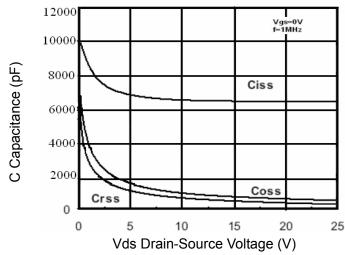


Figure 7 Capacitance vs Vds

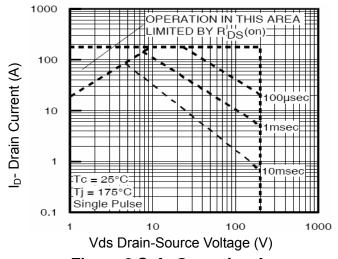


Figure 8 Safe Operation Area

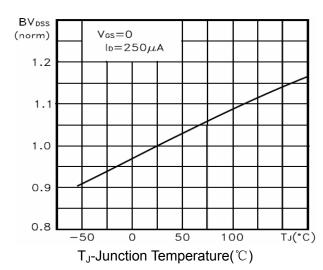


Figure 9 BV_{DSS} vs Junction Temperature

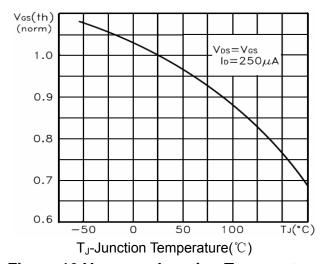


Figure 10 V_{GS(th)} vs Junction Temperature

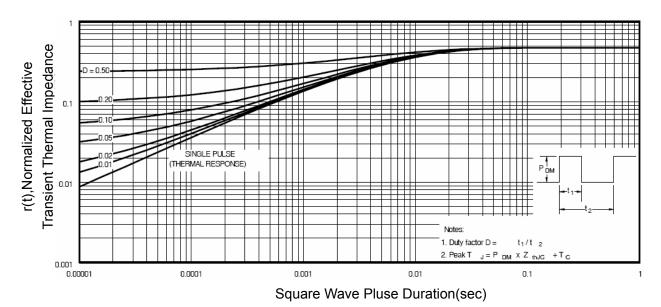


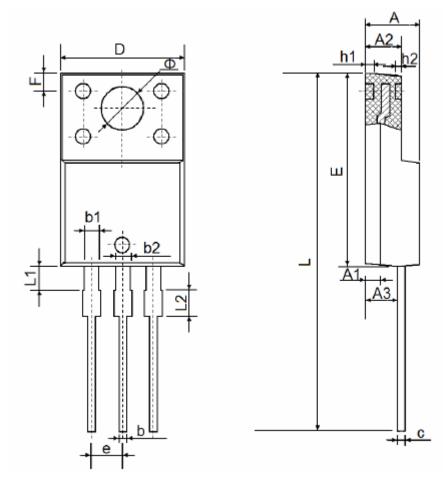
Figure 11 Normalized Maximum Transient Thermal Impedance

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TO-220F Package Information



Ob. al	Dimensions	n Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.300	4.700	0.169	0.185	
A1	1.300	DREF	0.051REF		
A2	2.800	3.200	0.110 0.126		
A3	2.500	2.900	0.098	0.114	
b	0.500	0.750	0.020	0.030	
b1	1.100	1.350	0.043	0.053	
b2	1.500	1.750	0.059	0.069	
С	0.500	0.750	0.020	0.030	
D	9.960	10.360	0.392	0.408	
E	14.800	15.200	0.583	0.598	
e	2.540	TYP.	0.100TYP		
F	2.700	REF	0.106REF		
Φ	3.500	DREF	0.138REF		
h1	0.800	REF	0.031REF		
h2	0.500REF		0.020REF		
L	28.000	28.400	1.102	1.118	
L1	1.700	1.900	0.067	0.075	
L2	1.900	2.100	0.075	0.083	



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